National Semiconductor

54F/74F373
Octal Transparent Latch with TRI-STATE® Outputs

General Description

The 'F373 consists of eight latches with TRI-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state.

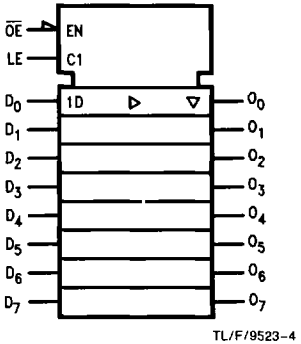
Features

- Eight latches in a single package
- TRI-STATE outputs for bus interfacing

Ordering Code: See Section 5

Logic Symbols

IEEE/IEC



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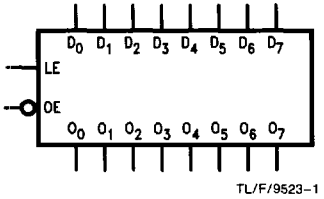

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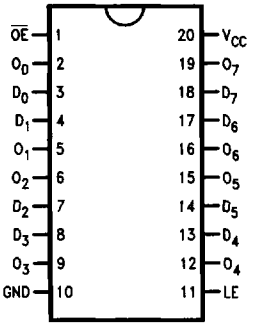
Connection Diagrams

Pin Assignment for DIP, SOIC and Flatpak



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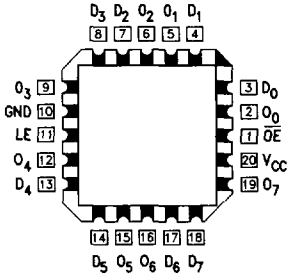
Pin Assignment for LCC and PCC



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Unit Loading/Fan Out: See Section 2 for U.L. definitions

Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/−0.6 mA
LE	Latch Enable Input (Active HIGH)	1.0/1.0	20 μA/−0.6 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 μA/−0.6 mA
O_0–O_7	TRI-STATE Latch Outputs	150/40 (33.3)	−3 mA/24 mA (20 mA)

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Functional Description

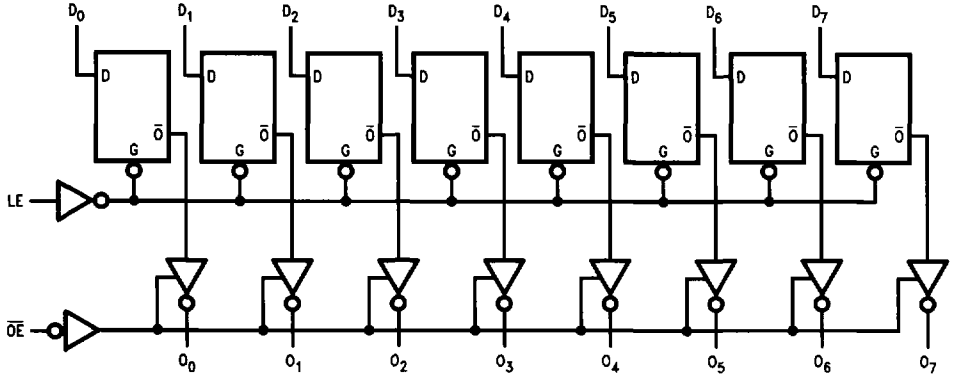
The 'F373 contains eight D-type latches with TRI-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The TRI-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Output
LE	$\overline{OE}$	D_n	O_n
H	L	H	H
H	L	L	L
L	L	X	O_n (no change)
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance State

Logic Diagram



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Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
TRI-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F Min	54F/74F Typ	54F/74F Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54F 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		54F 10% V_{CC}	2.4					I_{OH} = −3 mA
		74F 10% V_{CC}	2.5					I_{OH} = −1 mA
		74F 10% V_{CC}	2.4					I_{OH} = −3 mA
		74F 5% V_{CC}	2.7					I_{OH} = −1 mA
		74F 5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	54F 10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
		74F 10% V_{CC}			0.5			I_{OL} = 24 mA
I_{IH}	Input HIGH Current				20	μA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				100	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	μA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	μA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				250	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				500	μA	0.0V	V_{OUT} = V_{CC}
I_{CCZ}	Power Supply Current			38	55	mA	Max	V_O = HIGH Z

AC Electrical Characteristics: See Section 2 for Waveforms and Load Configurations

Symbol	Parameter	74F $T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF			54F $T_A, V_{CC} =$ Mil $C_L = 50$ pF		74F $T_A, V_{CC} =$ Com $C_L = 50$ pF		Units	Fig No
		Min	Typ	Max	Min	Max	Min	Max		
t_{PLH}	Propagation Delay	3.0	5.3	7.0	3.0	8.5	3.0	8.0	ns	2-3
t_{PHL}	D_n to O_n	2.0	3.7	5.0	2.0	7.0	2.0	6.0		
t_{PLH}	Propagation Delay	5.0	9.0	11.5	5.0	15.0	5.0	13.0	ns	2-3
t_{PHL}	LE to O_n	3.0	5.2	7.0	3.0	8.5	3.0	8.0		
t_{PZH}	Output Enable Time	2.0	5.0	11.0	2.0	13.5	2.0	12.0	ns	2-5
t_{PZL}		2.0	5.6	7.5	2.0	10.0	2.0	8.5		
t_{PHZ}	Output Disable Time	1.5	4.5	6.5	1.5	10.0	1.5	7.5	ns	2-5
t_{PLZ}		1.5	3.8	5.0	1.5	7.0	1.5	6.0		

AC Operating Requirements: See Section 2 for Waveforms

Symbol	Parameter	74F $T_A = +25°C$ $V_{CC} = +5.0V$		54F $T_A, V_{CC} =$ Mil		74F $T_A, V_{CC} =$ Com		Units	Fig No
		Min	Max	Min	Max	Min	Max		
$t_s(H)$	Setup Time, HIGH or LOW	2.0		2.0		2.0		ns	2-6
$t_s(L)$	D_n to LE	2.0		2.0		2.0			
$t_h(H)$	Hold Time, HIGH or LOW	3.0		3.0		3.0			
$t_h(L)$	D_n to LE	3.0		4.0		3.0			
$t_w(H)$	LE Pulse Width, HIGH	6.0		6.0		6.0		ns	2-4